



Product data sheet

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LM2576XX-MS/LM2576HVXX-MS HF

Semiconductor Compiance

Features

- 3.3V, 5V, 12V, 15V, and adjustable output versions
- Adjustable version output voltage range
- 1.23V to 37V (57V for HV version) $\pm 4\%$ max over line and load conditions
- Guaranteed 3A output current
- Wide input voltage range, 40V up to57V for HV version
- Requires only 4 external components
- 52 kHz fixed frequency oscillator
- TTL shutdown capability, low power standby mode
- High efficiency
- Uses readily available standard inductors
- Thermal shutdown and current limit protection

Applications

- Simple high-efficiency step-down (buck)regulator
- Efficient pre-regulator for linear regulators
 - On-card switching regulators
 - Positive to negative converter (Buck-Boost)

Typical application Figure 1.(Fixed Output Voltage Versions)



Package Types





Pin Assignments



Pin Descriptions

Name	Description
Vin	Input supply voltage
Output	Switching output
Gnd	Ground
Feedback	Output voltage feedback
ON/OFF	ON/OFF shutdown Active is "Low" or floating

Block Diagram



3.3V, R2 =1.7K 5V, R2 = 3.1K 12V, R2 = 8.84K 15V, R2 =11.3K For ADJ, Version R1 = Open, R2 =0Ω

Ordering information

Temperature	Output Voltage, V					Package Type
Range	3.3	5.0	12	15	ADJ	
-40°C ≤ T _A	LM2576HVS-3.3	LM2576HVS -5.0	LM2576HVS -12	LM2576HVS -15	LM2576HVS -ADJ	TO-263
≤ 125°C	LM2576S -3.3	LM2576S - 5.0	LM2576S -12	LM2576S -15	LM2576S -ADJ	10-200
	LM2576HVT -3.3	LM2576HVT -5.0	LM2576HVT-12	LM2576HVT-15	LM2576HVT-ADJ	TO-220
	LM2576T -3.3	LM2576T - 5.0	LM2576T -12	LM2576T -15	LM2576T -ADJ	10-220



Absolute Maximum Ratings (Note 1)

Parameter	Maximum	Units
Maximum Supply Voltage		
LM2576	45	V
LM2576HV	57	
ON/OFF Pin Input Voltage	$-0.3V \le V \le +V_{IN}$	
Output Voltage to Ground (Steady State)	-1	V
Power Dissipation	Internally Limited	W
Storage Temperature Range	-65 to +150	°C
Maximum Junction Temperature	150	°C
Minimum ESD Rating (C= 100pF, R = 1.5 k Ω)	2	kV
Lead Temperature (Soldering, 10 Seconds)	260	°C

Operating Ratings

Parameter	Value	Units
Temperature Range	-40 ≤ TJ ≤ +125	°C
LM2576/LM2576HV	_	
Supply Voltage		
LM2576	40	V
LM2576HV	57	

Electrical Characteristics LM2576- 3.3, LM2576HV -3.3 Specifications with standard type face are for T_J = 25°C, and those with **boldface type** apply over full Operating Temperature Range.

Symbol	Parameter	Conditions	LM LM2	2576 -3.3 576HV -3.3	Units (Limits)
			Тур	Limit (Note 2)	
SYSTEM P	ARAMETERS (Note	3) Test Circuit Figure 2			
V _{OUT}	Output Voltage	V _{IN} =12V, I _{LOAD} =0.5A Circuit of <i>Figure 2</i>	3.3	3.234 3.366	V V(Min) V(Max)
V _{OUT}	Output Voltage LM2576	$6V \le V_{IN} \le 40V$, $0.5A \le I_{LOAD} \le$ 3A Circuit of <i>Figure</i> 2	3.3	3.168/ 3.135 3.432/ 3.465	V V(Min) V(Max)
Vout	Output Voltage LM2576HV	$6V \le V_{IN} \le 60V$, $0.5A \le I_{LOAD} \le$ 3A Circuit of <i>Figure 2</i>	3.3	3.168/ 3.135 3.450/ 3.482	V V(Min) V(Max)
η	Efficiency	V _{IN} =12V, I _{LOAD} =3A	75		%

Electrical CharacteristicsLM2576 -5.0,LM2576HV-5.0

Specifications with standard type face are for T_J = 25°C, and those with **boldface type** apply over full Operating Temperature Range.

Symbol	Parameter	Conditions	LM: LM2	2576 -5.0 576HV -5.0	Units (Limits)
			Тур	Limit (Note 2)	
SYSTEM PA	SYSTEM PARAMETERS (Note 3) Test Circuit Figure 2				
V _{OUT}	Output Voltage	V _{IN} =12V, I _{LOAD} =0.5A Circuit of <i>Figure</i> 2	5.0	4.900 5.100	V V(Min) V(Max)
V _{OUT}	OutputVoltage LM2576	$0.5A \le I_{LOAD} \le 3A,$ $8V \le V_{IN} \le 40V$ Circuit of <i>Figure 2</i>	5.0	4.800/ 4.750 5.200/ 5.250	V V(Min) V(Max)
V _{OUT}	Output Voltage LM2576HV	$0.5A \le I_{LOAD} \le 3A,$ $8V \le V_{IN} \le 60V$ Circuit of <i>Figure 2</i>	5.0	4.800/ 4.750 5.225/ 5.275	V V(Min) V(Max)
η	Efficiency	V _{IN} =12V, I _{LOAD} =3A	77		%



Electrical Characteristics LM2576 -12, LM2576HV -12

Specifications with standard type face are for $T_J = 25^{\circ}$ C, and those with **boldface type** apply over full Operating Temperature Range.

Symbol	Parameter	Conditions	LM2576 -12 LM2576HV -12		Units (Limits)
			Тур	Limit(Note 2)	
SYSTEM PA	SYSTEM PARAMETERS (Note 3) Test Circuit Figure 2				
V _{OUT}	Output Voltage	V _{IN} =25V, I _{LOAD} =0.5A Circuit of <i>Figure 2</i>	12	11.76 12.24	V V(Min) V(Max)
V _{OUT}	OutputVoltage LM2576	$0.5A \le I_{LOAD} \le 3A,$ $15V \le V_{IN} \le 40V$ Circuit of <i>Figure 2</i>	12	11.52/ 11.40 12.48/ 12.60	V V(Min) V(Max)
Vout	Output Voltage LM2576HV	$0.5A \le I_{LOAD} \le 3A,$ $15V \le V_{IN} \le 60V$ Circuit of <i>Figure 2</i>	12	11.52/ 11.40 12.54/ 12.66	V V(Min) V(Max)
η	Efficiency	V _{IN} =15V, I _{LOAD} =3A	88		%

Electrical Characteristics LM2576 -15, LM2576HV -15

Specifications with standard type face are for T_J = 25°C, and those with **boldface type** apply over full Operating Temperature Range.

Symbol	Parameter	Conditions	LM2 LM25	576 -15 76HV -15	Units (Limits)	
			Тур	Limit (Note 2)		
SYSTEM PA	SYSTEM PARAMETERS (Note 3) Test Circuit Figure 2					
V _{OUT}	Output Voltage	V _{IN} =25, I _{LOAD} =0.5A Circuit of <i>Figure 2</i>	15	14.70 15.30	V V(Min) V(Max)	
V _{OUT}	OutputVoltage LM2576	$0.5A \le I_{LOAD} \le 3A$, $18 \le V_{IN} \le 40V$ Circuit of <i>Figure 2</i>	15	14.40/ 14.25 15.60/ 15.75	V V(Min) V(Max)	
V _{OUT}	Output Voltage LM2576HV	$0.5A \le I_{LOAD} \le 3A,$ $18 \le V_{IN} \le 60V$ Circuit of <i>Figure 2</i>	15	14.40/ 14.25 15.68/ 15.83	V V(Min) V(Max)	
η	Efficiency	V _{IN} =18V, I _{LOAD} =3A	88		%	

Electrical Characteristics LM2576 -ADJ, LM2576HV -ADJ

Specifications with standard type face are for $T_J = 25^{\circ}$ C, and those with **boldface type** apply over full Operating Temperature Range.

Symbol	Parameter	Conditions	LM2 LM257	576 -ADJ 6HV -ADJ	Units (Limits)
			Тур	Limit(Note 2)	
SYSTEM PARAMETERS (Note 3) Test Circuit Figure 2					
V _{OUT}	Feedback Voltage	$V_{IN} = 12V$, $I_{LOAD} = 0.5A$, $V_{OUT} = 5V$ Circuit of <i>Figure 2</i>	1.230	1.217 1.243	V V(Min) V(Max)
V _{OUT}	Feedback Voltage LM2576	$0.5A \le I_{LOAD} \le 3A$, $8V \le V_{IN} \le 40V V_{OUT} = 5V$ Circuit of <i>Figure 2</i>	1.230	1.193/1 .180 1.267/1 .280	V V(Min) V(Max)
V _{OUT}	Feedback Voltage LM2576HV	$0.5A \le I_{LOAD} \le 3A, 8V \le V_{IN} \le 60V, V_{OUT} = 5V$ Circuit of <i>Figure 2</i>	1.230	1.193/1 .180 1.273/1 .286	V V(Min) V(Max)
η	Efficiency	V _{IN} =12V, I _{LOAD} =3A, V _{OUT} =5V	77		%



All Output VoltageVersions

Electrical Characteristics

Specifications with standard type face are for $T_J = 25^{\circ}$ C, and those with **boldface type** apply over full Operating Temperature Range. Unless otherwise specified, $V_{IN} = 12V$ for the 3.3V, 5V, and Adjustable version, $V_{IN} = 25V$ for the 12V version, and $V_{IN} = 30V$ for the 15V version, $I_{LOAD} = 500$ mA.

Symbol	Parameter	Conditions	tions LM2576 -XX Units LM2576HV-XX (Limits)		
			Тур	Limit (Note 2)	
DEVICE P	ARAMETERS				
l _b	Feedback Bias Current	V _{OUT} =5V (Adjustable Version Only)	50	100/ 500	nA
f _o	Oscillator Frequency	(Note 8)	52	47/ 42 58/ 63	kHz kHz(Min) kHz(Max)
V _{SAT}	Saturation Voltage	I _{OUT} =3A (Note 4)	1.4	1.8/ 2.0	V V(Max)
DC	Max Duty Cycle (ON)	(Note 5)	98	93	% %(Min)
I _{CL}	Current Limit	(Notes 4, 8)	5.8	4.2/ 3.5 6.9/ 7.5	A A(Min) A(Max)
ΙL	Output Leakage Current	(Notes 6, 7): Output = -1V Output = -1V	7.5	2 30	mA(Max) mA mA(Max)
lα	Quiescent Current	(Note 6)	5	10	mA mA(Max)
I _{STBY}	Standby Quiescent Current	ON/OFF Pin = 5V (OFF)	50	200	μΑ μΑ(Max)
ON/OFF C	ONTROL				
V _{IH}	_	V _{OUT} = 0V	1.4	2.2/ 2.4	V(Min)
V _{IL}	ON/OFF Pin Logic Input Level	V _{OUT} = Nominal Output Voltage	1.2	1.0/ 0.8	V(Max)
Ін	ON/OFF Pin Input	ON/OFF Pin = 5V (OFF)	12	30	μΑ μΑ(Max)
IIL .	Current	– ON/OFF Pin = 0V (ON)	0	10	μΑ μΑ(Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics.

Note 2: All limits guaranteed at room temperature (standa rd type face) and at temperature extremes (bold type face).

Note 3: External components such as the catch diode, inductor, input and output capacitors can affect switching regulator system performance. When the LM2576/LM2576HV is used as shown in the *Figure 2* test circuit, system performance will be as shown in system parameters section of Electrical Characteristics.

Note 4: Output pin sourcing current. No diode, inductor or capacitor connected to output.

Note 5: Feedback pin removed from output and connected to 0V.

Note 6: Feedback pin removed from output and connected to +12V for the Adjustable, 3.3V, and 5V, versions, and +25V for the 12V and 15V versions, to force the output transistor OFF.

Note 7: V_{IN} =40V (60V for high voltage version).

Note 8: The oscillator frequency reduces to approximately 11 kHz in the event of an output short or an overload which causes the regulated output voltage to drop approximately 40% from the nominal output voltage. This self protections feature lowers the average power dissipation of the IC by lowering the minimum duty cycle from 5% down to approximately 2%.



LM2576XX-MS/LM2576HVXX-MS HF

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Typical Performance Characteristics (Circuit of Figure 2)



Line Regulation



Dropout Voltage



Standby Quiescent Current



Switch Saturation Voltage



Minimum Operating Voltage





Quiescent Current



Current Limit



Oscilator Frequency



Feedback Voltage vs Duty Cycle



Efficiency

100						
05		LOAD	= 3A		T. =2	5°C
20			7	LOA D	= 200)mA
90	15V (OUT	-	-		
85						
80	51/	-		-		
75			_			
70	_	1				
65	LO	= 3	A		1	
60				LOAD	= 20	OmA
60 (0 1	0 2	0 3	0 4	0 5	0 60
	IN	і і і т		TAC		

Quiescent Current vs Duty Cycle

20.0

17.5

15.0

12.5



Adjustable Version Only

 $V_{IN} = 7V$





Maximum Power Dissipation





Switching Waveforms



Load Transient



V_{OUT} =15V

A: Output Pin Voltage, 50V/div

B: Output Pin Current, 2A/div

C: Inductor Current, 2A/div

D: Output Ripple Voltage, 50mV/div,

AC-Coupled

Horizontal Time Base: 5µs/div



LM2576XX-MS/LM2576HVXX-MS HF

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Test Circuit and Layout Guidelines

As in any switching regulator, layout is very important. Rapidly switching currents associated with wiring inductance generate voltage transients which can cause problems. For minimal inductance and ground loops, the length of the leads indicated by heavy lines should be kept as short as possible.

Single-point grounding (as indicated) or ground plane construction should be used for best results. When using the Adjustable version, physically locate the programming resistors near the regulator, to keep the sensitive feedback wiring short.

Fixed Output Voltage Versions (Figure 2a)



where V_{REF} = 1.23V, R1 between 1k and 5k



Package Information

(1) TO220-5L



Course al	Dimensions I	mensions In Millimeters		s In Inches
Symbol	Min.	Max.	Min.	Max.
A	4.06	4.83	0.160	0.190
b	0.76	1.02	0.030	0.040
С	0.36	0.64	0.014	0.025
D	14.22	15.49	0.560	0.610
E	9.78	10.54	0.385	0.415
е	1.57	1.85	0.062	0.073
e(1)	6.68	6.93	0.263	0.273
F	1.14	1.40	0.045	0.055
H(1)	5.46	6.86	0.215	0.270
J(1)	2.29	3.18	0.090	0.125
L	13.21	14.73	0.520	0.580
ΦP	3.68	3.94	0.145	0.155
Q	2.54	2.92	0.100	0.115



COMMON DIMENSIONS

MAX

4.70

1.32

0.15

0.97

0.76

8.89

10.39

10,54

7.11

14.35

1.27

 \overline{a}

-

0.76

373

13°

0.25

1.32

MIN

0.175

0.048

0.000

0.028

0.015

0.330

0.390

0.395

0.260

-

-

-

0.042

-

-

-

7.

0.004

INCH

NDM

0.180

0.050

0,343

0.400

0,400

0.270

0.067BSC

-

0,078

0,058REF

0,134REF

0,030

0.047

-

7.

3.

10*

3.

0.007

MAX

0,185

0.052

0.006

0.038 0.030

0.350

0.410

0.415

0.280

0.565

0,050

-

-

0.052

0.030

-

13*

0.010

Package Information

(2) TO263-5







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